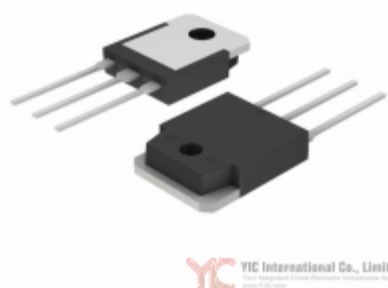



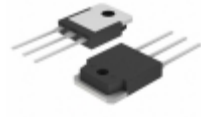
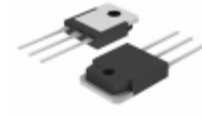


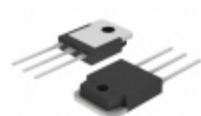


	<b>FQA10N80C</b>	
	<b>Hersteller-Teilenummer:</b>	FQA10N80C
	<b>Hersteller / Marke:</b>	AMI Semiconductor / ON Semiconductor
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 800V 10A TO-3P
	<b>Datenblätter:</b>	 <a href="#">FQA10N80C.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
<p>Image may be representation. See specs for product details.</p>	<b>Lagerzustand:</b>	New original, 2184 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS

### Spezifikationen

Teilenummer	FQA10N80C
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 800V 10A TO-3P
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	2184 pcs Stock
detaillierte Beschreibung	N-Channel 800V 10A (Tc) 240W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3P
Verlustleistung (max)	240W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10A (Tc)
Rds On (Max) @ Id, Vgs	1.1 Ohm @ 5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	58nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2800pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)






























FQA10N80C ist neu im Original, Suche FQA10N80C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA10N80C AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQA10N80C: Info@Y-IC.com

Sie können auch interessiert sein:

 <b>FQA10N80C_F109</b> Fairchild/ON Semiconductor FQA10N80C_F109 Fairchild/ON Semiconductor	 <b>FQA10N60C</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 10A TO-3P	 <b>FQA10N80</b> Fairchild/ON Semiconductor MOSFET N-CH 800V 9.8A TO-3P	 <b>FQA10N60C</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 10A TO-3P
 <b>FQA10N80C</b> Fairchild/ON Semiconductor MOSFET N-CH 800V 10A TO-3P	 <b>FQA10N80C-F109</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 10A TO-3P	 <b>FQA10N80_F109</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 9.8A TO-3P	 <b>FQA10N60</b> FSC FQA10N60 FSC

### heiße Teile

Mehr

 FQA10N60C	 FQA10N60C	 FQA10N80C	 FQA10N80C_F109	 FQA11N90
 FQA11N90	 FQA11N90C	 FQA11N90C	 FQA11N90C	 FQA11N90C_F109
 FQA11N90_F109	 FQA12N60C	 FQA12P20	 FQA12P20	 FQA13N50
 FQA13N50	 FQA13N50C	 FQA13N50C	 FQA13N50C_F109	 FQA13N80
 FQA13N80	 FQA13N80_F109	 FQA140N10	 FQA140N10	 FQA14N30
 FQA14N30	 FQA160N08	 FQA160N08	 FQA16N50	 FQA16N50
 FQA170N06	 FQA170N06	 FQA18N40	 FQA18N50	 FQA19N20C
 FQA19N20C	 FQA19N20L	 FQA19N20L	 FQA19N60	 FQA19N60
 FQA20N40	 FQA20N40	 FQA20N50	 FQA20N60	 FQA20N80
 FQA24N50	 FQA24N50	 FQA24N50F	 FQA24N50F	 FQA24N60

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited